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Microsemi.

## Power Matters<sup>™</sup>

Home JAN2N6438 (#23955)

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- ► Applications Directory
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### Overview Diagrams

# Electrical Rating Symbol Min Typ Max Unit DC Current Gain HFE 30.00 120.00 Turn Off Time (nS) t<sub>off</sub> 1250.00 ns

| Maximum Electrical Rating             | Symbol           | Min | Тур | Max    | Unit |
|---------------------------------------|------------------|-----|-----|--------|------|
| Collector Current (dc)                | I <sub>C</sub>   |     |     | 25.00  | А    |
| Collector-Emitter Voltage (Base Open) | V <sub>CEO</sub> |     |     | 120.00 | V    |
| Junction Temperature (°C)             | T <sub>J</sub>   |     |     | 200.00 | °C   |

This part can be found in the following product categories:

- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ PNP Transistor
- Discretes ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ PNP Transistor

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